Low-ohmic four-pole double-throw analog switch

Rev. 1 — 20 January 2014

Product data sheet

1. General description

The NX3DV2567-Q100 is a four-pole double-throw analog switch (4PDT) optimized for switching WLAN-SIM supply, data and control signals. It has one digital select input (S) and four switches each with two independent input/outputs (nY0 and nY1) and a common input/output (nZ). Schmitt-trigger action at S, makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 1.4 V to 4.3 V.

Lower-level logic signals can drive pin S without a significant increase in supply current I_{CC} , due to a low input voltage threshold. This characteristic makes it possible for the NX3DV2567-Q100 to switch 4.3 V signals with a 1.8 V digital controller, eliminating the need for logic level translation.

The NX3DV2567-Q100 allows signals with amplitude up to V_{CC} to be transmitted from nZ to nY0 or nY1; or from nY0 or nY1 to nZ.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - ◆ Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance for supply path:
 - 0.5 Ω (typical) at V_{CC} = 1.8 V
 - 0.45 Ω (typical) at V_{CC} = 2.7 V
- Low ON resistance for data path:
 - 7 Ω (typical) at V_{CC} = 1.8 V
 - 6 Ω (typical) at V_{CC} = 2.7 V
- Low ON capacitance for data path
- Wide –3 dB bandwidth > 160 MHz
- Break-before-make switching
- High noise immunity
- ESD protection:
 - MIL-STD-883, method 3015 Class 3A exceeds 4000 V
 - HBM JESD22-A114F Class 3A exceeds 4000 V
 - MIL-STD-883, method 3015 Class 3A I/O to GND exceeds 7000 V
 - ◆ HBM JESD22-A114F Class 3A I/O to GND exceeds 7000 V
 - CDM AEC-Q100-011 revision B exceeds 1000 V
- CMOS low-power consumption



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- Latch-up performance exceeds 100 mA per JESD 78B Class II Level A
- 1.8 V control logic at V_{CC} = 3.6 V
- Control input accepts voltages above supply voltage
- Very low supply current, even when input is below V_{CC}
- High current handling capability (350 mA continuous current under 3.3 V supply for supply path switch)

3. Applications

- Cell phone, PDA, digital camera, printer and notebook
- LCD monitor, TV and set-top box

4. Ordering information

Table 1. Ordering information

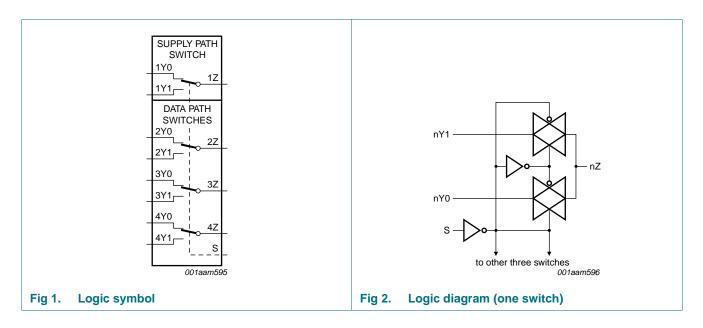
Type number	Package			
	Temperature range	Name	Description	Version
NX3DV2567HR-Q100	–40 °C to +125 °C	HXQFN16U	plastic thermal enhanced extremely thin quad flat package; no leads; 16 terminals; UTLP based; body 3 x 3 x 0.5 mm	SOT1039-1

5. Marking

Table 2. Marking codes

Type number	Marking code
NX3DV2567HR-Q100	D60

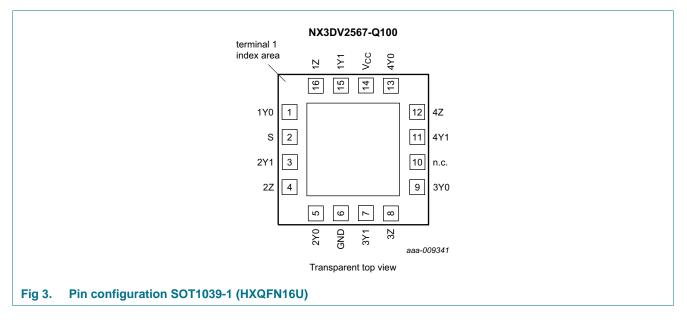
6. Functional diagram



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7. Pinning information

7.1 Pinning



7.2 Pin description

Table 3.	Pin	description

Symbol	Pin	Description
1Y0	1	independent input or output (supply switch)
2Y0, 3Y0, 4Y0	5, 9, 13	independent input or output (data switch)
S	2	select input
1Y1	15	independent input or output (supply switch)
2Y1, 3Y1, 4Y1	3, 7, 11	independent input or output (data switch)
1Z	16	common output or input (supply switch)
2Z, 3Z, 4Z	4, 8, 12	common output or input (data switch)
GND	6	ground (0 V)
n.c.	10	not connected
V _{CC}	14	supply voltage

8. Functional description

Table 4.Function table^[1]

Input S	Channel on
L	nY0
Н	nY1

[1] H = HIGH voltage level; L = LOW voltage level.

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9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
VI	input voltage	select input S	<u>[1]</u> –0.5	+4.6	V
V _{SW}	switch voltage		2 -0.5	$V_{CC} + 0.5$	V
I _{IK}	input clamping current	V _I < -0.5 V	-50	-	mA
I _{SK}	switch clamping current	$V_{I} < -0.5$ V or $V_{I} > V_{CC}$ + 0.5 V	-	±50	mA
I _{SW}	switch current	supply path switch			
		V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; source or sink current	-	±350	mA
		V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current	-	±500	mA
		data path switch			
		V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; source or sink current	-	±128	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$	[3] _	250	mW

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

[3] Above 135 °C, the value of P_{tot} derates linearly with 16.9 mW/K.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		1.4	4.3	V
VI	input voltage	select input S	0	4.3	V
V _{SW}	switch voltage		<u>[1]</u> 0	V _{CC}	V
T _{amb}	ambient temperature		-40	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	V_{CC} = 1.4 V to 4.3 V	[2] _	200	ns/V

[1] To avoid sinking GND current from terminal nZ when switch current flows in terminal nYn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal nZ, no GND current flows from terminal nYn. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to control signal levels.

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11. Static characteristics

Table 7. Static characteristics

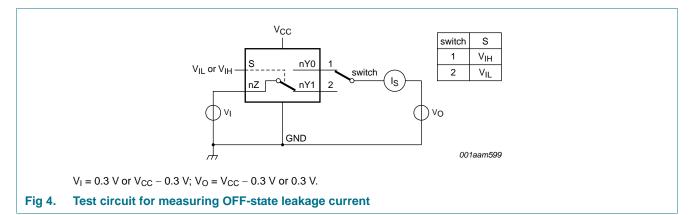
At recommended operating conditions; voltages are referenced to GND (ground 0 V).

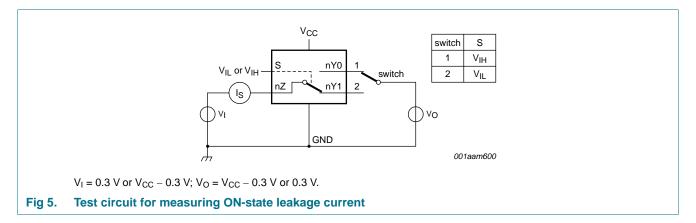
Symbol	Parameter	Conditions	Ta	_{mb} = 25	°C	T _{amb} =	–40 °C to	+125 °C	Uni
			Min	Тур	Max	Min	Мах (85 °С)	Max (125 °C)	
ViH	HIGH-level	$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	0.9	-	-	0.9	-	-	V
	input voltage	$V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$	0.9	-	-	0.9	-	-	V
		V_{CC} = 2.3 V to 2.7 V	1.1	-	-	1.1	-	-	V
		$V_{CC} = 2.7 \text{ V} \text{ to } 3.6 \text{ V}$	1.3	-	-	1.3	-	-	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	1.4	-	-	1.4	-	-	V
VIL	LOW-level	$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	-	-	0.3	-	0.3	0.3	V
	input voltage	V _{CC} = 1.65 V to 1.95 V	-	-	0.4	-	0.4	0.3	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.4	-	0.4	0.4	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	-	0.5	-	0.5	0.5	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	0.6	-	0.6	0.6	V
I	input leakage current	select input S; V _I = GND to 4.3 V; V _{CC} = 1.4 V to 4.3 V	-	-	-	-	±0.5	±1	μA
S(OFF)	OFF-state leakage	nY0 and nY1 port; see <u>Figure 4</u>							
current	current	V_{CC} = 1.4 V to 3.6 V	-	-	±5	-	±50	±500	nA
		V_{CC} = 3.6 V to 4.3 V	-	-	±10	-	±50	±500	nA
S(ON)	ON-state leakage current	nZ port; V _{CC} = 1.4 V to 3.6 V; see <u>Figure 5</u>							
		V_{CC} = 1.4 V to 3.6 V	-	-	±5	-	±50	±500	nA
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	±10	-	±50	±500	nA
СС	supply current	$V_I = V_{CC}$ or GND; $V_{SW} = GND$ or V_{CC}							
		$V_{CC} = 3.6 V$	-	-	100	-	500	5000	nA
		$V_{CC} = 4.3 V$	-	-	150	-	800	6000	nA
۱ _{CC}	additional	$V_{SW} = GND \text{ or } V_{CC}$							
	supply current	$V_{I} = 2.6 \text{ V}; V_{CC} = 4.3 \text{ V}$	-	2.0	4.0	-	7	7	μA
		$V_{I} = 2.6 \text{ V}; V_{CC} = 3.6 \text{ V}$	-	0.35	0.7	-	1	1	μA
		$V_{I} = 1.8 \text{ V}; V_{CC} = 4.3 \text{ V}$	-	7.0	10.0	-	15	15	μA
		V _I = 1.8 V; V _{CC} = 3.6 V	-	2.5	4.0	-	5	5	μA
		V _I = 1.8 V; V _{CC} = 2.5 V	-	50	200	-	300	500	nA
Cı	input capacitance		-	1	-	-	-	-	pF
C _{S(OFF)}	OFF-state	supply path switch	-	35	-	-	-	-	pF
- (- · · /	capacitance	data path switch	-	3	-	-	-	-	pF
C _{S(ON)}	ON-state	supply path switch	-	130	-	-	-	-	, pF
-(0.1)	capacitance	data path switch	-	16	-	-	-	-	pF

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11.1 Test circuits





11.2 ON resistance

Table 8.ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 7 to Figure 12.

Symbol	Parameter	Conditions		–40 °C to	o +85 °C	$T_{amb} = -40$	$T_{amb} = -40 \ ^{\circ}C \ to \ +125 \ ^{\circ}C$		
			Min	Typ <mark>[1]</mark>	Max	Min	Max		
Supply p	oath switch		•			'	1		
R _{ON}	ON resistance	$V_I = GND$ to V_{CC} ; $I_{SW} = 100$ mA; see <u>Figure 6</u>							
		V_{CC} = 1.8 V; V_{SW} = 0 V, 1.8 V	-	0.5	0.75	-	0.85	Ω	
		V_{CC} = 2.7 V; V_{SW} = 0 V, 2.3 V	-	0.45	0.7	-	0.8	Ω	
ΔR_{ON}	ON resistance	$V_I = GND$ to V_{CC} ; $I_{SW} = 100 \text{ mA}$ [2]							
	mismatch between channels	$V_{CC} = 2.7 \text{ V}; V_{SW} = 0 \text{ V}$	-	0.1	-	-	-	Ω	

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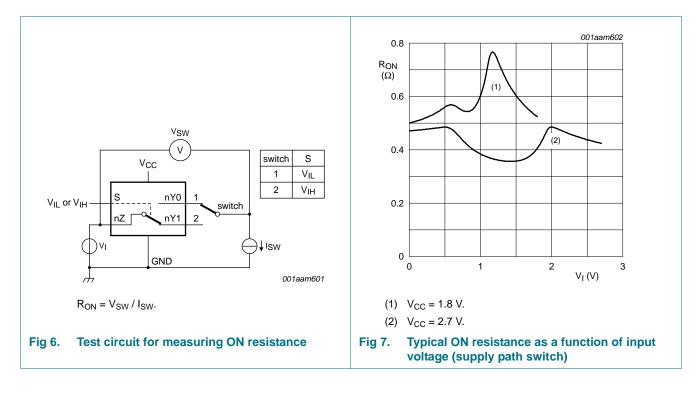
At recom	mended operatin	g conditions; voltages are referenced	to GND	(ground	= 0 V); fo	r graphs see	Figure 7 to <u>Fig</u>	<u>ure 12</u> .	
Symbol	Parameter	Conditions	T _{amb} =	-40 °C to	o +85 °C	T_{amb} = -40 °	mb = −40 °C to +125 °C		
		Min	Typ <mark>[1]</mark>	Max	Min	Max			
Data pat	h switches								
R _{ON} O	ON resistance	$V_I = GND$ to V_{CC} ; $I_{SW} = 20$ mA; see Figure 6							
		V_{CC} = 1.8 V; V_{SW} = 0 V, 1.8 V	-	7.0	10.0	-	11.0	Ω	
		V_{CC} = 2.7 V; V_{SW} = 0 V, 2.3 V	-	6.0	9.5	-	10.5	Ω	
ΔR_{ON}	ON resistance	$V_{I} = GND \text{ to } V_{CC}; I_{SW} = 20 \text{ mA}$ [2]							
b	mismatch between channels	$V_{CC} = 2.7 \text{ V}; V_{SW} = 0 \text{ V}$	-	0.2	-	-	-	Ω	

Table 8. ON resistance ...continued

[1] Typical values are measured at $T_{amb} = 25 \ ^{\circ}C$.

[2] Measured at identical V_{CC}, temperature and input voltage.

11.3 ON resistance test circuit and graphs



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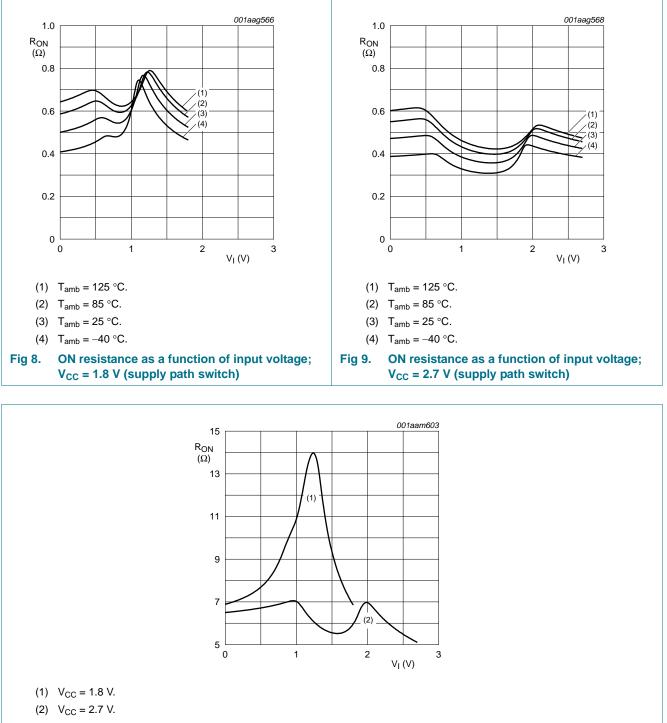
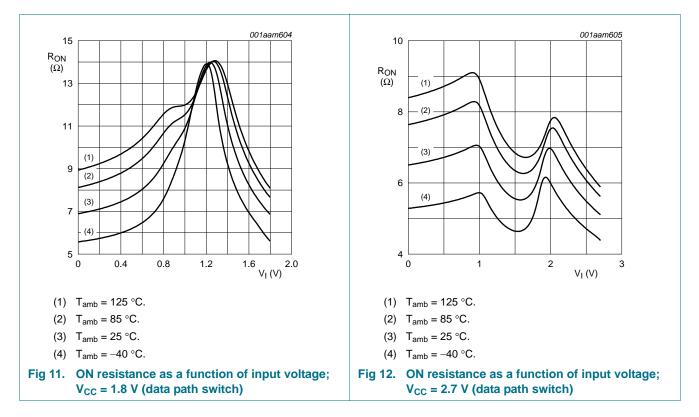


Fig 10. Typical ON resistance as a function of input voltage (data path switch)

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12. Dynamic characteristics

Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit, see Figure 15.

Symbol	Parameter	Conditions		25 °C	_	-40	–40 °C to +125 °C			
			Min	Typ <mark>[1]</mark>	Max	Min	Max (85 °C)	Max (125 °C)		
Supply p	oath switch									
t _{en}	enable time	S to 1Z or 1Y0, 1Y1; see <u>Figure 13</u>								
		V_{CC} = 1.4 V to 1.6 V	-	41	90	-	120	120	ns	
		V_{CC} = 1.65 V to 1.95 V	-	30	70	-	80	90	ns	
		V_{CC} = 2.3 V to 2.7 V	-	20	45	-	50	55	ns	
		V_{CC} = 2.7 V to 3.6 V	-	19	40	-	45	50	ns	
		V_{CC} = 3.6 V to 4.3 V	-	19	40	-	45	50	ns	
t _{dis}	disable time	S to 1Z or 1Y0, 1Y1; see <u>Figure 13</u>								
		V_{CC} = 1.4 V to 1.6 V	-	24	70	-	80	90	ns	
		V_{CC} = 1.65 V to 1.95 V	-	15	55	-	60	65	ns	
		V_{CC} = 2.3 V to 2.7 V	-	9	25	-	30	35	ns	
		V_{CC} = 2.7 V to 3.6 V	-	8	20	-	25	30	ns	
		V_{CC} = 3.6 V to 4.3 V	-	8	20	-	25	30	ns	

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Symbol	Parameter	Conditions	Conditions		25 °C		-40	°C to +12	5 °C	Uni
			Min	Typ[1]	Мах	Min	Max (85 °C)	Max (125 °C)		
b-m	break-before-make	see Figure 14	[2]							
	time	V_{CC} = 1.4 V to 1.6 V		-	20	-	9	-	-	ns
		V_{CC} = 1.65 V to 1.95 V		-	17	-	7	-	-	ns
		V_{CC} = 2.3 V to 2.7 V		-	13	-	4	-	-	ns
		V_{CC} = 2.7 V to 3.6 V		-	11	-	3	-	-	ns
		V_{CC} = 3.6 V to 4.3 V		-	11	-	2	-	-	ns
Data patl	h switch									
en	enable time	S to nZ or nYn; see <u>Figure 13</u>								
		V_{CC} = 1.4 V to 1.6 V		-	40	90	-	120	120	ns
		V_{CC} = 1.65 V to 1.95 V		-	29	70	-	80	90	ns
		V_{CC} = 2.3 V to 2.7 V		-	20	45	-	50	55	ns
		V_{CC} = 2.7 V to 3.6 V		-	19	40	-	45	50	ns
		$V_{CC} = 3.6 \text{ V} \text{ to } 4.3 \text{ V}$		-	19	40	-	45	50	ns
dis	disable time	S to nZ or nYn; see <u>Figure 13</u>								
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		-	21	70	-	80	90	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		-	13	55	-	60	65	ns
		V_{CC} = 2.3 V to 2.7 V		-	8	25	-	30	35	ns
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		-	7	20	-	25	30	ns
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$		-	7	20	-	25	30	ns
b-m	break-before-make	see Figure 14	[2]							
	time	V_{CC} = 1.4 V to 1.6 V		-	23	-	9	-	-	ns
		V_{CC} = 1.65 V to 1.95 V		-	19	-	7	-	-	ns
		V_{CC} = 2.3 V to 2.7 V		-	15	-	4	-	-	ns
		V_{CC} = 2.7 V to 3.6 V		-	13	-	3	-	-	ns
		$V_{CC} = 3.6 \text{ V} \text{ to } 4.3 \text{ V}$		-	12	-	2	-	-	ns

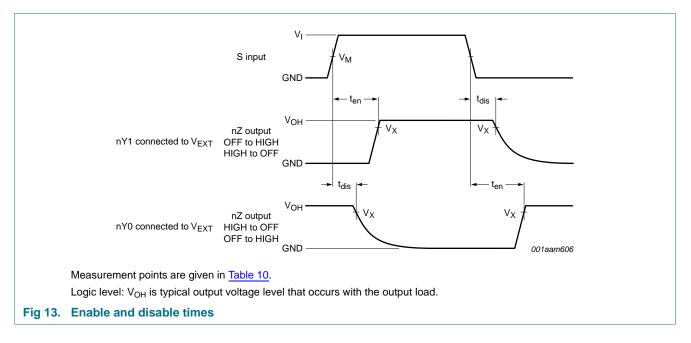
Table 9. Dynamic characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit, see Figure 15.

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.5 V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

[2] Break-before-make guaranteed by design.

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12.1 Waveform and test circuits

Table 10. Measurement points

Supply voltage	Input	Output
V _{cc}	V _M	V _X
1.4 V to 4.3 V	0.5V _{CC}	0.9V _{OH}

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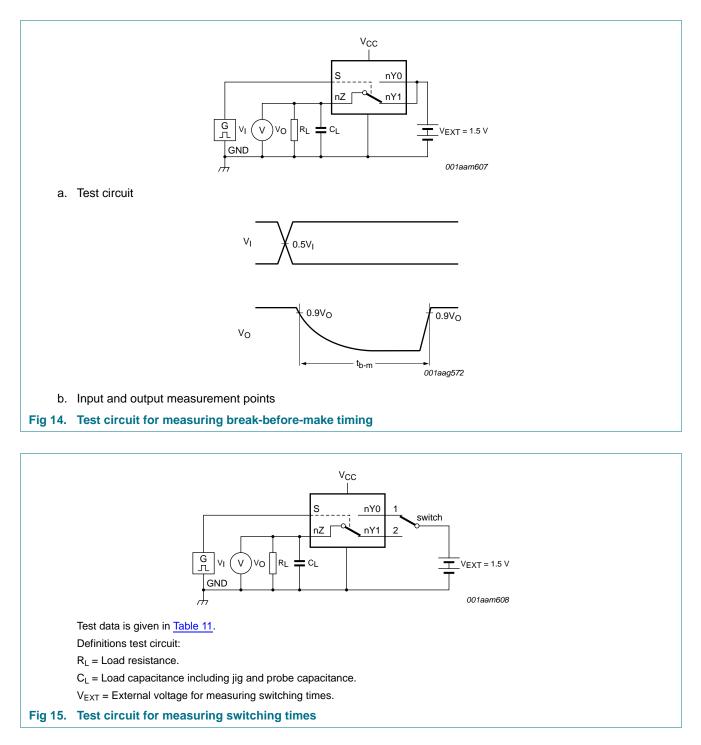


Table 11. Test data

Supply voltage	Input		e Input Load		
V _{cc}	VI	t _r , t _f	CL	RL	
1.4 V to 4.3 V	V _{CC}	\leq 2.5 ns	35 pF	50 Ω	

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12.2 Additional dynamic characteristics

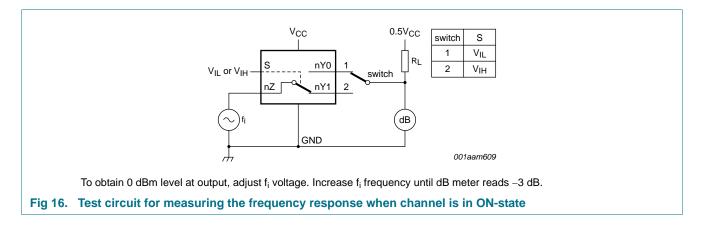
Table 12. Additional dynamic characteristics

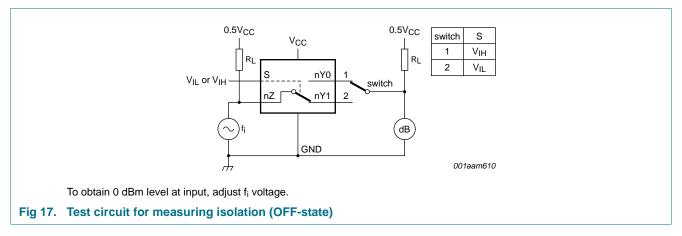
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $V_I = GND$ or V_{CC} (unless otherwise specified); $t_r = t_f \le 2.5$ ns; $T_{amb} = 25$ °C.

Symbol	Parameter	Conditions	Mir	า Тур	Max	Unit
Data pat	h switch					
f _(-3dB)	–3 dB frequency response	$R_L = 50 \Omega$; see Figure 16	[1]			
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		- 330	-	MHz
α_{iso}	isolation (OFF-state)	$f_i = 10 \text{ MHz}; \text{ R}_L = 50 \Omega; \text{ see } \frac{\text{Figure 17}}{10000000000000000000000000000000000$	[1]			
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		-60	-	dB
Xtalk crosstal	crosstalk	between switches; $f_i = 10 \text{ MHz}$; $R_L = 50 \Omega$; see <u>Figure 18</u>	[1]			
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		-60	-	dB
Q _{inj}	charge injection	$f_i = 1 \text{ MHz}; C_L = 0.1 \text{ nF}; R_L = 1 \text{ M}\Omega; V_{gen} = 0 \text{ V}; R_{gen} = 0 \Omega; \text{ see } \frac{\text{Figure 19}}{10000000000000000000000000000000000$				
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	•	- 10	-	рС

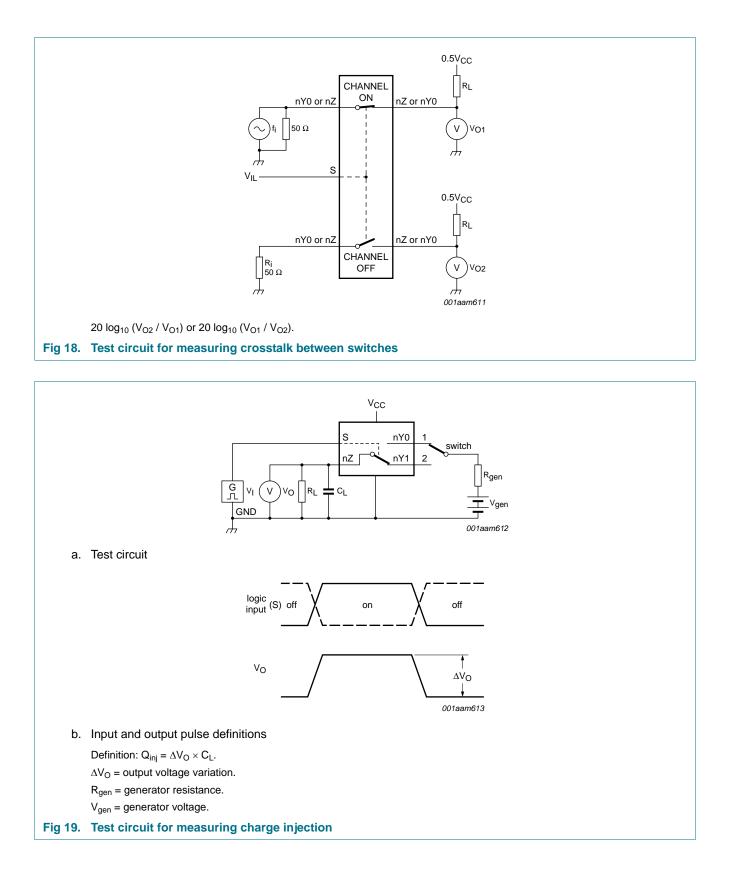
[1] f_i is biased at 0.5V_{CC}.

12.3 Test circuits





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13. Package outline

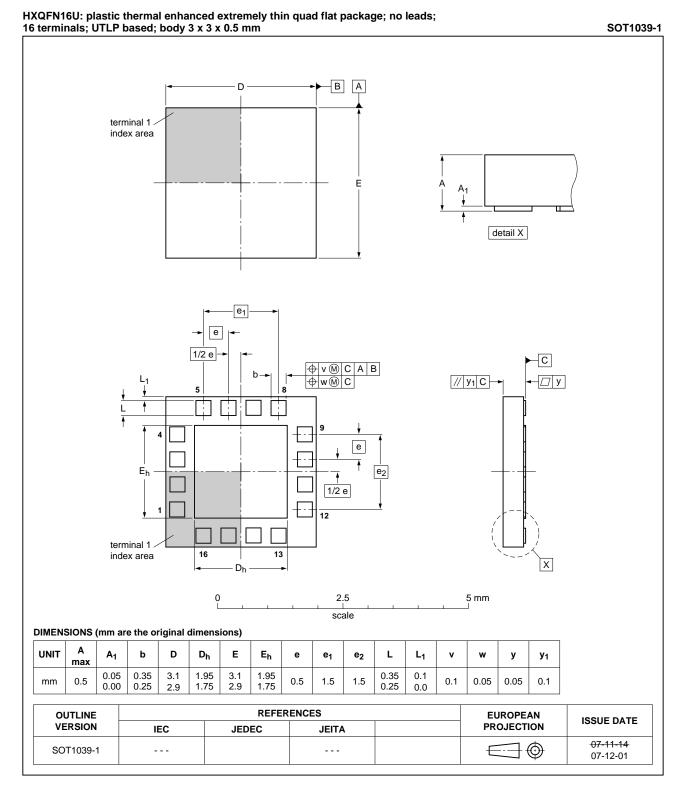


Fig 20. Package outline SOT1039-1 (HXQFN16U)

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Product data sheet

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14. Abbreviations

Table 13.	Abbreviations		
Acronym	Description		
CDM	Charged Device Model		
CMOS	Complementary Metal-Oxide Semiconductor		
ESD	ElectroStatic Discharge		
HBM	Human Body Model		
MM	Machine Model		
PDA	Personal Digital Assistant		
TTL	Transistor-Transistor Logic		

15. Revision history

Table 14. Revision his	Revision history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3DV2567_Q100 v.1	20140120	Product data sheet	-	-

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16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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